Tem perature Dependence of the B and G ap of Sem iconducting C arbon N anotubes

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The temperature dependence of the band gap of sem iconducting single-wall carbon nanotubes (SW NTs) is calculated by direct evaluation of electron-phonon couplings within a \frozen-phonon" scheme. An interesting diameter and chirality dependence of $E_g(T)$ is obtained, including non-monotonic behavior for certain tubes and distinct \fram ily" behavior. These results are traced to a strong and complex coupling between band-edge states and the lowest-energy optical phonon modes in SW NTs. The $E_g(T)$ curves are modeled by an analytic function with diameter and chirality dependent parameters; these provide a valuable guide for system atic estimates of $E_g(T)$ for any given SW NT.M agnitudes of the temperature shifts at 300 K are smaller than 12 meV and should not a ect (n;m) assignments based on optical measurements.

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The tem perature dependence of the band gap (E_g) is one of the fundam ental signatures of a sem iconductor, providing in portant insights into the nature and strength of electron-phonon (e-p) interactions. The rst m easurem ents of E_g (T) date from the dawn of the sem iconductor era [1]. Typically, E_g (T) curves show a monotonic decrease with tem perature that is non-linear at low T and linear at su ciently high T [2, 3].

Sem iconducting carbon nanotubes are relatively novel sem iconductor m aterials [4], with a variety of potential applications. Despite intensive research since their discovery, it has only recently become possible to perform m easurem ents of the optical gap in individual single-wall carbon nanotubes (SW NTs) [5, 6, 7, 8, 9, 10]. Such measurements, combined with information from vibrational spectroscopy, provide a route to (n;m) assignment of SW NT s [5, 8, 9]. Understanding E_a (T) for nanotubes is extrem ely im portant in this context, since experim ents are usually performed at room -tem perature and (n;m) assignments are often guided by comparisons between observed optical transition patterns and the corresponding predictions from calculations at T = 0 K . M oreover, the E_q (I) signature could provide extra information for those assignm ents.

A lthough it has been demonstrated that many-body quasiparticle and excitonic e ects are crucial for the correct description of the photoexcited states and for a quantitative understanding of such optical measurements [11], the single-particle gap is still a fundam ental quantity because: (i) it is the starting point for more elaborate descriptions and (ii) trends in the single-particle gap are often preserved by such rements. Therefore, this work is devoted to describing the tem perature dependence of the single-particle band gap of sem iconducting SW NTs. From the calculated results for 18 di erent SW NTs, a com plex dependence of E_g (T) on chirality and diam eter is found, with an unsual non-monotonic behavior for certain classes of tubes. This behavior arises from the di erent set of the single-particle set of the single set of the single set of the single set of the substantiation of the single set of the set of the single set of the set of

ences in sign of the e-p coupling associated to low -energy optical phonons. A model relation describing E_g (I) for any given SW NT, as a function of diam eter and chirality, is proposed.

The tem perature dependence of E_g at constant pressure can be separated into harm onic and anharm onic contributions: $(@E_g=@T)_P = (@E_g=@T)_{har} + (@E_g=@T)_{anh}$. The harm onic term arises from the e-p interaction evaluated at the ground-state geom etry. The anharm onic term is due to therm al expansion. The harm onic term is usually the more di cult one to evaluate and it has challenged theorists for many years [12, 13, 14, 15, 16]. We follow closely the formulation of A llen, Heine and C ardona [14, 15, 16] to calculate E_g (T) for sem iconducting SW NTs. In the spirit of the adiabatic approxim ation [14], we write the shift of an electronic eigenenergy $E_{n,k}$ of band n and wavevector k due to static atom ic displacements from equilibrium as a second-order Taylor expansion:

$$E_{n,k} = u \quad r E_{n,k} + \frac{1}{2}u \quad D \quad u;$$
 (1)

where u is a 3N -coordinate displacement vector and D is the corresponding (3N 3N) Hessian matrix (N is the number of atom s). As usual, we express the displacements as a sum over norm almodes [17]:

$$u(;) = \frac{X}{2M !_{j}} - \frac{1}{2M !_{j}} = "_{j}(;)(a^{y}_{j} + a_{j}); \quad (2)$$

where u(;) is the displacement along direction of atom in the unit cell, with mass M. The electronphonon couplings will be directly evaluated using the \frozen-phonon" scheme [18], therefore the sum only runs over zone-center modes j, with frequency $!_j$. In this approach, a su ciently large supercell (equivalent to a ne Brillouin Zone sampling) will be needed to achieve convergence. The a_j^y and a_j are creation and destruction

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operators for phonons, and $"_{\rm j}(\ ;\)$ are components of the properly norm alized polarization vectors.

We now substitute Eq. (2) into Eq. (1) and perform a therm all average [17]. In the harm onic approximation, the linear term in u vanishes and the nalresult is analogous to Ref.[15]'s:

$$E_{n,k} = \sum_{j=1}^{X} \frac{\partial E_{n,k}}{\partial n_{j}} (n_{j} + \frac{1}{2});$$
(3)

where $n_j = (e^{-!j} 1)^{-1}$ is the Bose-E instein occupation number of phonon mode j and the e-p coupling coe cient $@E_{n,k} = @n_j$ is given by

$$\frac{\partial E_{n,k}}{\partial n_{j}} = \frac{1}{2} x_{j} \quad D_{j} \mathbf{x}$$
(4)

where $x_j(;) = (\sim=M !_j)^{1=2} "_j(;)$ are \frozenphonon" displacements. From Eq. (1), this is simply the quadratic contribution to $E_{n,k}$ when the atom s are displaced along a certain frozen-phonon x_j . So, in practice, $@E_{n,k}=@n_j$ is calculated by performing electronic structure calculations for x_j and by averaging the obtained energy shifts so as to eliminate the linear term.

Structural relaxations and phonon calculations are perform ed using the extended Terso Brenner interatom ic potential [19]. Electronic structure is calculated using a multiple-neighbor, non-orthogonal tight-binding m ethod [20, 21]. Calculations are perform ed for 18 di erent sem iconducting SW NT's with diam eters d = 7.6 13:5 A and spanning the entire range of chiralities: (6,5), (7,5), (7,6), (8,6), (8,3), (8,4), (9,4), (9,5), (9,1), (11,1), (10,2), (12,2), (10,0), (11,0), (13,0), (14,0), (16,0) and (17,0).[22]

Fig. 1 shows the calculated (dots) values of E_{α} (T) = Е_q (Т) E_q (0) for all the 18 SW NTs studied. The lines are best ts to our model relation of Eq. (6), to be discussed below. For clarity, results are grouped into four panels according to sim ilar values of the chiral angle . The tem perature dependence of the band gap is relatively sm all com pared to bulk sem iconductors: From the set of calculated SW NTs, the largest value of $E_{\alpha}(0) = E_{\alpha}(300 \text{K})$ is 12 meV for the (16,0) tube, with $(dE_{g}=dT)_{300K} = 5:2 \ 10^{2} \text{ meV}/\text{K}$. A strong and apparently complicated chirality and diameter dependence emerges:SWNTswith = (nm)mod3=2(full dots) have, in general, sm aller gap shifts than = 1 tubes (open dots). M ost interestingly, som e = 2 SW NT swith small chiral angles show a non-monotonic gap variation with tem perature that is positive for small T and negative for larger T . Som e of these trends, in particular the overall magnitude of the shifts and their -oscillations, are observed in recent photolum inescence m easurem ents in suspended SW NTs [23].

It is challenging to explain this interesting and complex behavior within a united framework. The rst step is to analyze the contributions to E_g (T) from the different phonon modes. This information is contained in the e-p

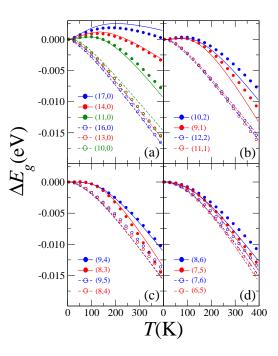


FIG.1: Calculated and tted E $_{\rm g}$ (T). Full dots and lines correspond to = 2 SW NTs, whereas open dots and dashed lines correspond to = 1 SW NTs.

spectral function for the gap, g^2F , de ned as [15]

$$g^{2}F() = \frac{X}{i} \frac{\partial E_{g}}{\partial n_{j}} (1) = \frac{\partial E_{g}}{\partial n_{j}} (1)$$

Note that $(E_g=0n_j)$, de ned as the di erence between coupling coe cients for the two band-edge states (from Eq. (4)), can be positive or negative.

In Fig. 2(a) and (b) (lower panels) we plot g^2F for the (10,0) and (11,0) SW NTs, which are prototype examples of = 1 and = 2 tubes, respectively. The plots are restricted to the low-energy phonon branches (shown in the upper panels), the relevant ones to describe E_q (T) for T < 400 K.W e notice that g^2F (full black line) is highly structured, re ecting the complexity of the phonon dispersion of these materials, even at low energies. In particular, we nd that the low -energy optical \shape-deform ation" modes (SDM s) near provide the most important contributions to $q^2 F$ at low energies, shown by the red dashed lines. This fam ily of modes is derived, in a zone-folding scheme, from the outof-plane transverse-acoustical (ZA) branch of graphene and they deform the circular cross-section of the tubes into a sequence of shapes: ellipse (the so-called \squashing mode"), triangle, square, pentagon, etc. For the (10,0) tube, the contribution to q^2F from these modes is strongly negative and dom inates the full q^2F up to phonon energies equivalent to 500 K. For the (11,0), this contibution is positive and smaller, but still dom inates $g^2 F$ for T < 200 K.Beyond that tem perature, the negative contributions from other modes start to become important. This competition explains the non-

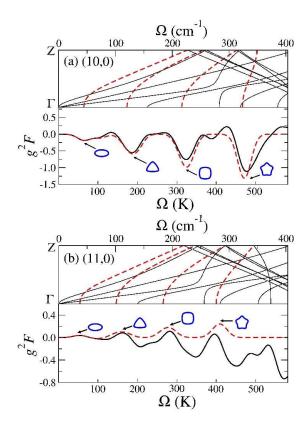


FIG.2:D in ensionless g^2F (low erpanels) and phonon spectra (upper panels) for (a) (10,0) and (b) (11,0) SW NTs. Lower panels: Full black lines are the total g^2F and red dashed lines are the contributions from the shape-deform ation m odes (SDM s) near . The g^2F is obtained from G aussian broadening (= 23 K) of individual phonon contributions. Shapes for each SDM are also shown in the gure. Upper panels: Phonon frequencies () m easured in both cm 1 and K.SDM branches are highlighted in red dashed lines.

m onotonic behavior and sm aller m agnitudes of E_g (T) shifts for = 2 SW NTs.

A pproxim ate m odel relations for E $_{\rm g}$ (T) are common in semiconductor physics [24]. Despite not being exact, they are useful tools for a quick assessment of E $_{\rm g}$ (T) for a given m aterial. We propose a model relation for E $_{\rm g}$ (T) of semiconducting SW NTs in the temperature range of T < 400 K as a two-phonon V in a model [25]:

$$E_{g}(T) = \frac{1}{e^{1}} + \frac{2}{e^{2}} + \frac{2}{e^{2}} + \frac{2}{2};$$
 (6)

where 1 and 2 ($_1 < _2$) are elective temperatures for the two \average phonons" and $_j _j = @E_g = @n_j$ are their elective e-p coupling coel cients. The resulting ts are shown in Fig. 1 as full (= 2) and dashed (= 1) lines. Note that this model is equivalent to replacing the highly structured spectral functions shown in Fig. 2 by only two delta functions for each tube. Therefore, the resulting ts will necessarily be approximate. Nonetheless, as we see from Fig.1, the largest deviation from numerical and model results is only 2 m eV in the whole T < 400 K range. M ore importantly, as we shall see below, we are able to obtain a completely coherent and physically justimed dependence of the parameters j and j on the SW NT's diameter and chirality.

We start by considering the parameter 1, the effective frequency for the lowest energy phonon modes. These modes dictate the low-temperature (T . 100 K) behavior of E_g(T). These are the SDMs, derived from the ZA branch of graphene. In graphene, this branch has a quadratic dispersion at low energies and momenta. Therefore, within a zone-folding description, we propose that the energies of these modes (and therefore 1) should scale as the inverse square of the nanotube diameter d (in dimensionless units, $d = \frac{1}{n^2 + m^2 + nm}$):

$$_{1} = \frac{A}{d^{2}} :$$
 (7)

Therefore, $_1$ depends only on diam eter and not on chirality.

The remaining parameters (1, 2 and 2) depend on chirality. The task of nding this dependence is enom ously facilitated by the following ansatz: Dependence on chirality can be expressed as polynomial expansions f() of a \chirality variable" = (1) cos(3). This ansatz is reminiscent of trigonal warping e ects in graphite [26, 27] and is justilled a posteriori by our numerical results. We consider up to 2nd-order term s:

$$f() = \frac{1}{1} + \frac{2}{2};$$
 (8)

where de nes the parameter under consideration.

The parameter $_1$ deserves special attention because it must embody the intriguing sign dependence of g^2F on

for the SDM s described above. We nd the following relation:

$$_{1} = {}^{0}_{1} + f_{1} ()d:$$
 (9)

The derivation of this result involves a fascinating connection between dynamical and static radial deform ations and will be presented elsewhere [28]. Sim ilar fam ily behavior" [27] and sign oscillations with occur for static deform ations induced by hydrostatic pressure [28] and uniaxial stress [29].

W e now turn to the chirality and diam eter dependence of $_2$ and $_2$. These parameters e ectively represent a large number of phonon modes that start to become \active" at somewhat higher temperatures (between 350 K and 500 K). In this energy range, the phonon DOS starts to become substantial, and we should expect that characteristics of particular nanotubes (chirality dependence) should gradually disappear and give rise to universal, graphite-like features. O fcourse, this is only exact in the lim it of large d, therefore, for the relatively narrow tubes considered here, it is wise to include some chirality dependence (in the form of Eq. 8) that decays with increasing diam eter. W e therefore propose the following expressions:

$$_{2} = \frac{1}{2} + \frac{f_{2}()}{d}$$
(10)

$$_{2} = \frac{1}{d} B + \frac{f_{2}()}{d} :$$
 (11)

The overall 1=d factor in $_2$ is simple to understand, since $_1 + _2 = \lim_{T + 1} \frac{dE_g}{dT}$, i.e., $_2$ is the graphite-like contribution to the limiting slope of E_g (T). We expect the high-tem perature renormalization of the graphite bands around the Ferm i point to be simply a rescaling of the Ferm i velocity. Since the sem iconducting SW NTs gaps are obtained, in a simpli ed view, by slicing the band structure of graphene, we expect the corresponding change in the gap to be proportional to the gap itself, i.e., to 1=d.

Equations (6-11) provide a ready-to-use recipe for estimating gap shifts with temperature for any nanotube in this diam eter range [30]. The 10 param eters are obtained by best ts: A = 9:45 10^3 K, 0_1 = 1:70 10^5 eV/K, 1_1 = 1:68 10^6 eV/K, 2_1 = 6:47 10^7 eV/K, 1_2 = 470 K, 2_1 = 1:06 10^3 K, 2_2 = 5:94 10^2 K, B = 4:54 10^4 eV/K, 2_1 = 2:68 10^3 eV/K and 2_2 = 2:23 10^5 eV/K.

Finally, we address the e ects of therm al expansion in $E_g(T)$. A vailable descriptions of therm al expansion of isolated SW NTs seem to be controversial [31, 32]. We propose that, for low-dimensional structures, one should describe therm al expansion e ects in the band gap in terms of anharm onic changes of internal coordinates (bond lengths and angles), rather than lattice constants. The C-C bond changes quite sim ilarly in all carbon structures (including diam ond), although the lattice constants m ay behave quite di erently [33]. We therefore use the well-established experimental data for the therm al expansion of diam ond [34], where the therm al expansion of the lattice m irrors closely the therm al expansion of the bond, to estimate the gap shifts due to anharm onic e ects. This leads to very small corrections in our calculated $E_g(T)$ values. For instance, the additional gap shift at 300 K for a (10,0) tube due to anharm onic e ects is only $0.2 \text{ meV} \cdot \text{W}$ e therefore can safely neglect these e ects in comparison with the harm onic contributions.

In conclusion, the calculated tem perature dependence of the band gap of sem iconducting carbon nanotubes shows a complex but system atic diam eter and chirality dependence. Most gap shifts at 300 K are negative and sm all (less than 12 m eV) with respect to 0 K. Therefore, tem perature e ects should not interfere with (n;m) assignments. Tubes with = 1 have generally larger shifts than = 2 tubes, and som e = 2 tubes with large chiral angles even display a non-monotonic E_g(T) curve. All these features are explained and reproduced by a two-phonon model relation, with diam eter-and chirality-dependent param eters.

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